



# Ultralow Noise XFET® Voltage References with Current Sink and Source Capability

ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

## FEATURES

Low noise (0.1 Hz to 10 Hz): 3.5  $\mu\text{V}$  p-p @ 2.5 V output

No external capacitor required

Low temperature coefficient

A Grade: 10 ppm/°C max

B Grade: 3 ppm/°C max

Load regulation: 15 ppm/mA

Line regulation: 20 ppm/V

Wide operating range

ADR430: 4.1 V to 18 V

ADR431: 4.5 V to 18 V

ADR433: 5.0 V to 18 V

ADR434: 6.1 V to 18 V

ADR435: 7.0 V to 18 V

ADR439: 6.5 V to 18 V

High output current: +30 mA/–20 mA

Wide temperature range: –40°C to +125°C

## APPLICATIONS

Precision data acquisition systems

High resolution data converters

Medical instruments

Industrial process control systems

Optical control circuits

Precision instruments

## GENERAL DESCRIPTION

The ADR43x series is a family of XFET voltage references featuring low noise, high accuracy, and low temperature drift performance. Using ADI's patented temperature drift curvature correction and XFET (eXtra implanted junction FET) technology, the ADR43x's voltage change versus temperature nonlinearity is minimized.

The XFET references operate at lower current (800  $\mu\text{A}$ ) and supply headroom (2 V) than buried-Zener references. Buried-Zener references require more than 5 V headroom for operations. The ADR43x XFET references are the only low noise solutions for 5 V systems.

The ADR43x series has the capability to source up to 30 mA and sink up to 20 mA of output current. It also comes with a TRIM terminal to adjust the output voltage over a 0.5% range without compromising performance. The ADR43x is available in the 8-lead mini SOIC and 8-lead SOIC packages.

### Rev. B

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## PIN CONFIGURATIONS

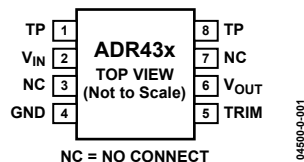


Figure 1. 8-Lead MSOP  
(RM Suffix)

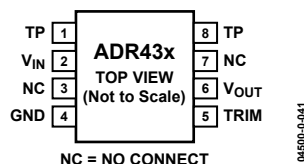


Figure 2. 8-Lead SOIC  
(R Suffix)

All versions are specified over the extended industrial temperature range (–40°C to +125°C).

Table 1. Selection Guide

| Model   | V <sub>OUT</sub> (V) | Accuracy (mV) | Temperature Coefficient (ppm/°C) |
|---------|----------------------|---------------|----------------------------------|
| ADR430B | 2.048                | ±1            | 3                                |
| ADR430A | 2.048                | ±3            | 10                               |
| ADR431B | 2.500                | ±1            | 3                                |
| ADR431A | 2.500                | ±3            | 10                               |
| ADR433B | 3.000                | ±1.4          | 3                                |
| ADR433A | 3.000                | ±4            | 10                               |
| ADR434B | 4.096                | ±1.5          | 3                                |
| ADR434A | 4.096                | ±5            | 10                               |
| ADR435B | 5.000                | ±2            | 3                                |
| ADR435A | 5.000                | ±6            | 10                               |
| ADR439B | 4.500                | ±2            | 3                                |
| ADR439A | 4.500                | ±5.4          | 10                               |

# ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

## TABLE OF CONTENTS

|                                           |    |                                                                      |    |
|-------------------------------------------|----|----------------------------------------------------------------------|----|
| Specifications.....                       | 3  | Applications.....                                                    | 16 |
| ADR430 Electrical Characteristics.....    | 3  | Output Adjustment .....                                              | 16 |
| ADR431 Electrical Characteristics.....    | 4  | Reference for Converters in Optical Network Control<br>Circuits..... | 16 |
| ADR433 Electrical Characteristics.....    | 5  | Negative Precision Reference without Precision Resistors ...         | 16 |
| ADR434 Electrical Characteristics.....    | 6  | High Voltage Floating Current Source .....                           | 17 |
| ADR435 Electrical Characteristics.....    | 7  | Kelvin Connections.....                                              | 17 |
| ADR439 Electrical Characteristics.....    | 8  | Dual Polarity References .....                                       | 17 |
| Absolute Maximum Ratings.....             | 9  | Programmable Current Source .....                                    | 18 |
| Package Type .....                        | 9  | Programmable DAC Reference Voltage .....                             | 18 |
| ESD Caution.....                          | 9  | Precision Voltage Reference for Data Converters.....                 | 19 |
| Typical Performance Characteristics ..... | 10 | Precision Boosted Output Regulator .....                             | 19 |
| Theory of Operation .....                 | 15 | Outline Dimensions .....                                             | 20 |
| Basic Voltage Reference Connections.....  | 15 | Ordering Guide .....                                                 | 21 |
| Noise Performance .....                   | 15 |                                                                      |    |
| Turn-On Time .....                        | 15 |                                                                      |    |

## REVISION HISTORY

### 9/04—Data Sheet Changed from Rev. A to Rev. B

|                                            |           |
|--------------------------------------------|-----------|
| Added New Grade .....                      | Universal |
| Changes to Specifications .....            | 3         |
| Replaced Figure 3, Figure 4, Figure 5..... | 10        |
| Updated Ordering Guide.....                | 21        |

### 6/04—Data Sheet Changed from Rev. 0 to Rev. A

|                                    |           |
|------------------------------------|-----------|
| Changes to Format .....            | Universal |
| Changes to the Ordering Guide..... | 20        |

### 12/03—Revision 0: Initial Version

## SPECIFICATIONS

### ADR430 ELECTRICAL CHARACTERISTICS

$V_{IN} = 4.1 \text{ V to } 18 \text{ V}$ ,  $I_{LOAD} = 0 \text{ mA}$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 2.

| Parameter                        | Symbol                         | Conditions                                                                                                                                                                                                                                            | Min   | Typ   | Max   | Unit                         |
|----------------------------------|--------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|-------|-------|------------------------------|
| Output Voltage                   |                                |                                                                                                                                                                                                                                                       |       |       |       |                              |
| B Grade                          | $V_O$                          |                                                                                                                                                                                                                                                       | 2.047 | 2.048 | 2.049 | V                            |
| A Grade                          | $V_O$                          |                                                                                                                                                                                                                                                       | 2.045 | 2.048 | 2.051 | V                            |
| Initial Accuracy                 |                                |                                                                                                                                                                                                                                                       |       |       |       |                              |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                       |       |       | 1     | mV                           |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                       |       |       | 0.05  | %                            |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                       |       |       | 3     | mV                           |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                       |       |       | 0.15  | %                            |
| Temperature Coefficient          |                                |                                                                                                                                                                                                                                                       |       |       |       |                              |
| SOIC-8 (B Grade)                 | $TCV_O$                        | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                        |       | 1     | 3     | ppm/ $^\circ\text{C}$        |
| SOIC-8 (A Grade)                 | $TCV_O$                        | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                        |       | 2     | 10    |                              |
| MSOP-8                           | $TCV_O$                        | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                        |       | 2     | 10    | ppm/ $^\circ\text{C}$        |
| Line Regulation                  | $\Delta V_O / \Delta V_{IN}$   | $V_{IN} = 4.1 \text{ V to } 18 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                           |       | 5     | 20    | ppm/V                        |
| Load Regulation                  | $\Delta V_O / \Delta I_{LOAD}$ | $I_{LOAD} = 0 \text{ mA to } 10 \text{ mA}$ , $V_{IN} = 5.0 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$<br>$I_{LOAD} = -10 \text{ mA to } 0 \text{ mA}$ , $V_{IN} = 5.0 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$ |       |       | 15    | ppm/mA                       |
| Quiescent Current                | $I_{IN}$                       | No load, $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                               |       | 560   | 800   | $\mu\text{A}$                |
| Voltage Noise                    | $e_N \text{ p-p}$              | 0.1 Hz to 10.0 Hz                                                                                                                                                                                                                                     |       | 3.5   |       | $\mu\text{V p-p}$            |
| Voltage Noise Density            | $e_N$                          | 1 kHz                                                                                                                                                                                                                                                 |       | 60    |       | $\text{nV}/\sqrt{\text{Hz}}$ |
| Turn-On Settling Time            | $t_R$                          | $C_{IN} = 0$                                                                                                                                                                                                                                          |       | 10    |       | $\mu\text{s}$                |
| Long-Term Stability <sup>1</sup> | $\Delta V_O$                   | 1,000 h                                                                                                                                                                                                                                               |       | 40    |       | ppm                          |
| Output Voltage Hysteresis        | $V_{O\_HYS}$                   |                                                                                                                                                                                                                                                       |       | 20    |       | ppm                          |
| Ripple Rejection Ratio           | RRR                            | $f_{IN} = 10 \text{ kHz}$                                                                                                                                                                                                                             |       | -70   |       | dB                           |
| Short Circuit to GND             | $I_{SC}$                       |                                                                                                                                                                                                                                                       |       | 40    |       | mA                           |
| Supply Voltage Operating Range   | $V_{IN}$                       |                                                                                                                                                                                                                                                       | 4.1   |       | 18    | V                            |
| Supply Voltage Headroom          | $V_{IN} - V_O$                 |                                                                                                                                                                                                                                                       | 2     |       |       | V                            |

<sup>1</sup> The long-term stability specification is noncumulative. The drift in subsequent 1,000 hour periods is significantly lower than in the first 1,000 hour period.

# ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

## ADR431 ELECTRICAL CHARACTERISTICS

$V_{IN} = 4.5 \text{ V}$  to  $18 \text{ V}$ ,  $I_{LOAD} = 0 \text{ mA}$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 3.

| Parameter                        | Symbol                         | Conditions                                                                                                                                                                                                                                              | Min   | Typ   | Max   | Unit                         |
|----------------------------------|--------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|-------|-------|------------------------------|
| Output Voltage                   |                                |                                                                                                                                                                                                                                                         |       |       |       |                              |
| B Grade                          | $V_O$                          |                                                                                                                                                                                                                                                         | 2.499 | 2.500 | 2.501 | V                            |
| A Grade                          | $V_O$                          |                                                                                                                                                                                                                                                         | 2.497 | 2.500 | 2.503 | V                            |
| Initial Accuracy                 |                                |                                                                                                                                                                                                                                                         |       |       |       |                              |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                         |       |       | 1     | mV                           |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                         |       |       | 0.04  | %                            |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                         |       |       | 3     | mV                           |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                         |       |       | 0.13  | %                            |
| Temperature Coefficient          |                                |                                                                                                                                                                                                                                                         |       |       |       |                              |
| SOIC-8 (B Grade)                 | $TCV_O$                        | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                          |       | 1     | 3     | ppm/ $^\circ\text{C}$        |
| SOIC-8 (A Grade)                 | $TCV_O$                        | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                          |       | 2     | 10    | ppm/ $^\circ\text{C}$        |
| MSOP-8                           | $TCV_O$                        | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                          |       | 2     | 10    | ppm/ $^\circ\text{C}$        |
| Line Regulation                  | $\Delta V_O / \Delta V_{IN}$   | $V_{IN} = 4.5 \text{ V}$ to $18 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                            |       | 5     | 20    | ppm/V                        |
| Load Regulation                  | $\Delta V_O / \Delta I_{LOAD}$ | $I_{LOAD} = 0 \text{ mA}$ to $10 \text{ mA}$ , $V_{IN} = 5.0 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$<br>$I_{LOAD} = -10 \text{ mA}$ to $0 \text{ mA}$ , $V_{IN} = 5.0 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$ |       |       | 15    | ppm/mA                       |
| Quiescent Current                | $I_{IN}$                       | No load, $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                 |       | 580   | 800   | $\mu\text{A}$                |
| Voltage Noise                    | $e_N$ p-p                      | 0.1 Hz to 10.0 Hz                                                                                                                                                                                                                                       |       | 3.5   |       | $\mu\text{V p-p}$            |
| Voltage Noise Density            | $e_N$                          | 1 kHz                                                                                                                                                                                                                                                   |       | 80    |       | $\text{nV}/\sqrt{\text{Hz}}$ |
| Turn-On Settling Time            | $t_R$                          | $C_{IN} = 0$                                                                                                                                                                                                                                            |       | 10    |       | $\mu\text{s}$                |
| Long-Term Stability <sup>1</sup> | $\Delta V_O$                   | 1,000 h                                                                                                                                                                                                                                                 |       | 40    |       | ppm                          |
| Output Voltage Hysteresis        | $V_{O\_HYS}$                   |                                                                                                                                                                                                                                                         |       | 20    |       | ppm                          |
| Ripple Rejection Ratio           | RRR                            | $f_{IN} = 10 \text{ kHz}$                                                                                                                                                                                                                               |       | -70   |       | dB                           |
| Short Circuit to GND             | $I_{SC}$                       |                                                                                                                                                                                                                                                         |       | 40    |       | mA                           |
| Supply Voltage Operating Range   | $V_{IN}$                       |                                                                                                                                                                                                                                                         | 4.5   |       | 18    | V                            |
| Supply Voltage Headroom          | $V_{IN} - V_O$                 |                                                                                                                                                                                                                                                         | 2     |       |       | V                            |

<sup>1</sup> The long-term stability specification is noncumulative. The drift in subsequent 1,000 hour periods is significantly lower than in the first 1,000 hour period.

# ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

## ADR433 ELECTRICAL CHARACTERISTICS

$V_{IN} = 5\text{ V to }18\text{ V}$ ,  $I_{LOAD} = 0\text{ mA}$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 4.

| Parameter                        | Symbol                         | Conditions                                                                                                                                                                                                                                | Min    | Typ   | Max    | Unit                         |
|----------------------------------|--------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|-------|--------|------------------------------|
| Output Voltage                   |                                |                                                                                                                                                                                                                                           |        |       |        |                              |
| B Grade                          | $V_O$                          |                                                                                                                                                                                                                                           | 2.9985 | 3.000 | 3.0015 | V                            |
| A Grade                          | $V_O$                          |                                                                                                                                                                                                                                           | 2.996  | 3.000 | 3.004  | V                            |
| Initial Accuracy                 |                                |                                                                                                                                                                                                                                           |        |       |        |                              |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                           |        |       | 1.5    | mV                           |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                           |        |       | 0.05   | %                            |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                           |        |       | 4      | mV                           |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                           |        |       | 0.13   | %                            |
| Temperature Coefficient          | $TCV_O$                        |                                                                                                                                                                                                                                           |        |       |        |                              |
| SOIC-8 (B Grade)                 |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                            |        | 1     | 3      | ppm/ $^\circ\text{C}$        |
| SOIC-8 (A Grade)                 |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                            |        | 2     | 10     | ppm/ $^\circ\text{C}$        |
| MSOP-8                           |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                            |        | 2     | 10     | ppm/ $^\circ\text{C}$        |
| Line Regulation                  | $\Delta V_O / \Delta V_{IN}$   | $V_{IN} = 5\text{ V to }18\text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                    |        | 5     | 20     | ppm/V                        |
| Load Regulation                  | $\Delta V_O / \Delta I_{LOAD}$ | $I_{LOAD} = 0\text{ mA to }10\text{ mA}$ , $V_{IN} = 6\text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$<br>$I_{LOAD} = -10\text{ mA to }0\text{ mA}$ , $V_{IN} = 6\text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$ |        |       | 15     | ppm/mA                       |
| Quiescent Current                | $I_{IN}$                       | No load, $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                   |        | 590   | 800    | $\mu\text{A}$                |
| Voltage Noise                    | $e_N\text{ p-p}$               | 0.1 Hz to 10.0 Hz                                                                                                                                                                                                                         |        | 3.75  |        | $\mu\text{V p-p}$            |
| Voltage Noise Density            | $e_N$                          | 1 kHz                                                                                                                                                                                                                                     |        | 90    |        | $\text{nV}/\sqrt{\text{Hz}}$ |
| Turn-On Settling Time            | $t_R$                          | $C_{IN} = 0$                                                                                                                                                                                                                              |        | 10    |        | $\mu\text{s}$                |
| Long-Term Stability <sup>1</sup> | $\Delta V_O$                   | 1,000 h                                                                                                                                                                                                                                   |        | 40    |        | ppm                          |
| Output Voltage Hysteresis        | $V_{O\_HYS}$                   |                                                                                                                                                                                                                                           |        | 20    |        | ppm                          |
| Ripple Rejection Ratio           | RRR                            | $f_{IN} = 10\text{ kHz}$                                                                                                                                                                                                                  |        | -70   |        | dB                           |
| Short Circuit to GND             | $I_{SC}$                       |                                                                                                                                                                                                                                           |        | 40    |        | mA                           |
| Supply Voltage Operating Range   | $V_{IN}$                       |                                                                                                                                                                                                                                           | 5      |       | 18     | V                            |
| Supply Voltage Headroom          | $V_{IN} - V_O$                 |                                                                                                                                                                                                                                           | 2      |       |        | V                            |

<sup>1</sup>The long-term stability specification is noncumulative. The drift in subsequent 1,000 hour periods is significantly lower than in the first 1,000 hour period.

# ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

## ADR434 ELECTRICAL CHARACTERISTICS

$V_{IN} = 6.1 \text{ V}$  to  $18 \text{ V}$ ,  $I_{LOAD} = 0 \text{ mA}$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 5.

| Parameter                        | Symbol                         | Conditions                                                                                                                                                                                                                                          | Min    | Typ   | Max    | Unit                         |
|----------------------------------|--------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|-------|--------|------------------------------|
| Output Voltage                   |                                |                                                                                                                                                                                                                                                     |        |       |        |                              |
| B Grade                          | $V_O$                          |                                                                                                                                                                                                                                                     | 4.0945 | 4.096 | 4.0975 | V                            |
| A Grade                          | $V_O$                          |                                                                                                                                                                                                                                                     | 4.091  | 4.096 | 4.101  | V                            |
| Initial Accuracy                 |                                |                                                                                                                                                                                                                                                     |        |       |        |                              |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                     |        |       | 1.5    | mV                           |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                     |        |       | 0.04   | %                            |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                     |        |       | 5      | mV                           |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                     |        |       | 0.13   | %                            |
| Temperature Coefficient          | $TCV_O$                        |                                                                                                                                                                                                                                                     |        |       |        |                              |
| SOIC-8 (B Grade)                 |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                      |        | 1     | 3      | ppm/ $^\circ\text{C}$        |
| SOIC-8 (A Grade)                 |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                      |        | 2     | 10     | ppm/ $^\circ\text{C}$        |
| MSOP-8                           |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                      |        | 2     | 10     | ppm/ $^\circ\text{C}$        |
| Line Regulation                  | $\Delta V_O / \Delta V_{IN}$   | $V_{IN} = 6.1 \text{ V}$ to $18 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                        |        | 5     | 20     | ppm/V                        |
| Load Regulation                  | $\Delta V_O / \Delta I_{LOAD}$ | $I_{LOAD} = 0 \text{ mA}$ to $10 \text{ mA}$ , $V_{IN} = 7 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$<br>$I_{LOAD} = -10 \text{ mA}$ to $0 \text{ mA}$ , $V_{IN} = 7 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$ |        |       | 15     | ppm/mA                       |
| Quiescent Current                | $I_{IN}$                       | No load, $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                             |        | 595   | 800    | $\mu\text{A}$                |
| Voltage Noise                    | $e_N \text{ p-p}$              | 0.1 Hz to 10.0 Hz                                                                                                                                                                                                                                   |        | 6.25  |        | $\mu\text{V p-p}$            |
| Voltage Noise Density            | $e_N$                          | 1 kHz                                                                                                                                                                                                                                               |        | 100   |        | $\text{nV}/\sqrt{\text{Hz}}$ |
| Turn-On Settling Time            | $t_R$                          | $C_{IN} = 0$                                                                                                                                                                                                                                        |        | 10    |        | $\mu\text{s}$                |
| Long-Term Stability <sup>1</sup> | $\Delta V_O$                   | 1,000 h                                                                                                                                                                                                                                             |        | 40    |        | ppm                          |
| Output Voltage Hysteresis        | $V_{O\_HYS}$                   |                                                                                                                                                                                                                                                     |        | 20    |        | ppm                          |
| Ripple Rejection Ratio           | RRR                            | $f_{IN} = 10 \text{ kHz}$                                                                                                                                                                                                                           |        | -70   |        | dB                           |
| Short Circuit to GND             | $I_{SC}$                       |                                                                                                                                                                                                                                                     |        | 40    |        | mA                           |
| Supply Voltage Operating Range   | $V_{IN}$                       |                                                                                                                                                                                                                                                     | 6.1    |       | 18     | V                            |
| Supply Voltage Headroom          | $V_{IN} - V_O$                 |                                                                                                                                                                                                                                                     | 2      |       |        | V                            |

<sup>1</sup> The long-term stability specification is noncumulative. The drift in subsequent 1,000 hour periods is significantly lower than in the first 1,000 hour period.

# ADR435 ELECTRICAL CHARACTERISTICS

$V_{IN} = 7\text{ V to }18\text{ V}$ ,  $I_{LOAD} = 0\text{ mA}$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 6.

| Parameter                        | Symbol                         | Conditions                                                                                                                                                                                                                                | Min   | Typ   | Max   | Unit                   |
|----------------------------------|--------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|-------|-------|------------------------|
| Output Voltage                   |                                |                                                                                                                                                                                                                                           |       |       |       |                        |
| B Grade                          | $V_O$                          |                                                                                                                                                                                                                                           | 4.998 | 5.000 | 5.002 | V                      |
| A Grade                          | $V_O$                          |                                                                                                                                                                                                                                           | 4.994 | 5.000 | 5.006 | V                      |
| Initial Accuracy                 |                                |                                                                                                                                                                                                                                           |       |       |       |                        |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                           |       |       | 2     | mV                     |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                           |       |       | 0.04  | %                      |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                           |       |       | 6     | mV                     |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                           |       |       | 0.12  | %                      |
| Temperature Coefficient          | $TCV_O$                        |                                                                                                                                                                                                                                           |       |       |       |                        |
| SOIC-8 (B Grade)                 |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                            |       | 1     | 3     | ppm/ $^\circ\text{C}$  |
| SOIC-8 (A Grade)                 |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                            |       | 2     | 10    | ppm/ $^\circ\text{C}$  |
| MSOP-8                           |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                            |       | 2     | 10    | ppm/ $^\circ\text{C}$  |
| Line Regulation                  | $\Delta V_O / \Delta V_{IN}$   | $V_{IN} = 7\text{ V to }18\text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                    |       | 5     | 20    | ppm/V                  |
| Load Regulation                  | $\Delta V_O / \Delta I_{LOAD}$ | $I_{LOAD} = 0\text{ mA to }10\text{ mA}$ , $V_{IN} = 8\text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$<br>$I_{LOAD} = -10\text{ mA to }0\text{ mA}$ , $V_{IN} = 8\text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$ |       |       | 15    | ppm/mA                 |
| Quiescent Current                | $I_{IN}$                       | No load, $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                   |       | 620   | 800   | $\mu\text{A}$          |
| Voltage Noise                    | $e_N$ p-p                      | 0.1 Hz to 10 Hz                                                                                                                                                                                                                           |       | 8     |       | $\mu\text{V p-p}$      |
| Voltage Noise Density            | $e_N$                          | 1 kHz                                                                                                                                                                                                                                     |       | 115   |       | nV/ $\sqrt{\text{Hz}}$ |
| Turn-On Settling Time            | $t_R$                          | $C_{IN} = 0$                                                                                                                                                                                                                              |       | 10    |       | $\mu\text{s}$          |
| Long-Term Stability <sup>1</sup> | $\Delta V_O$                   | 1,000 h                                                                                                                                                                                                                                   |       | 40    |       | ppm                    |
| Output Voltage Hysteresis        | $V_{O\_HYS}$                   |                                                                                                                                                                                                                                           |       | 20    |       | ppm                    |
| Ripple Rejection Ratio           | RRR                            | $f_{IN} = 10\text{ kHz}$                                                                                                                                                                                                                  |       | -70   |       | dB                     |
| Short Circuit to GND             | $I_{SC}$                       |                                                                                                                                                                                                                                           |       | 40    |       | mA                     |
| Supply Voltage Operating Range   | $V_{IN}$                       |                                                                                                                                                                                                                                           | 7     |       | 18    | V                      |
| Supply Voltage Headroom          | $V_{IN} - V_O$                 |                                                                                                                                                                                                                                           | 2     |       |       | V                      |

<sup>1</sup> The long-term stability specification is noncumulative. The drift in subsequent 1,000 hour periods is significantly lower than in the first 1,000 hour period.

# ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

## ADR439 ELECTRICAL CHARACTERISTICS

$V_{IN} = 6.5 \text{ V}$  to  $18 \text{ V}$ ,  $I_{LOAD} = 0 \text{ mA}$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 7.

| Parameter                        | Symbol                         | Conditions                                                                                                                                                                                                                                              | Min    | Typ   | Max    | Unit                   |
|----------------------------------|--------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|-------|--------|------------------------|
| Output Voltage                   |                                |                                                                                                                                                                                                                                                         |        |       |        |                        |
| B Grade                          | $V_O$                          |                                                                                                                                                                                                                                                         | 4.498  | 4.500 | 4.502  | V                      |
| A Grade                          | $V_O$                          |                                                                                                                                                                                                                                                         | 4.4946 | 4.500 | 4.5054 | V                      |
| Initial Accuracy                 |                                |                                                                                                                                                                                                                                                         |        |       |        |                        |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                         |        |       | 2      | mV                     |
| B Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                         |        |       | 0.04   | %                      |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                         |        |       | 5.4    | mV                     |
| A Grade                          | $V_{OERR}$                     |                                                                                                                                                                                                                                                         |        |       | 0.12   | %                      |
| Temperature Coefficient          | $TCV_O$                        |                                                                                                                                                                                                                                                         |        |       |        |                        |
| SOIC-8 (B Grade)                 |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                          |        | 1     | 3      | ppm/ $^\circ\text{C}$  |
| SOIC-8 (A Grade)                 |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                          |        | 2     | 10     | ppm/ $^\circ\text{C}$  |
| MSOP-8                           |                                | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                          |        | 2     | 10     | ppm/ $^\circ\text{C}$  |
| Line Regulation                  | $\Delta V_O / \Delta V_{IN}$   | $V_{IN} = 6.5 \text{ V}$ to $18 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                            |        | 5     | 20     | ppm/V                  |
| Load Regulation                  | $\Delta V_O / \Delta I_{LOAD}$ | $I_{LOAD} = 0 \text{ mA}$ to $10 \text{ mA}$ , $V_{IN} = 6.5 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$<br>$I_{LOAD} = -10 \text{ mA}$ to $0 \text{ mA}$ , $V_{IN} = 6.5 \text{ V}$<br>$-40^\circ\text{C} < T_A < +125^\circ\text{C}$ |        |       | 15     | ppm/mA                 |
| Quiescent Current                | $I_{IN}$                       | No load, $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                                                                                                                                                                                                 |        | 600   | 800    | $\mu\text{A}$          |
| Voltage Noise                    | $e_N \text{ p-p}$              | 0.1 Hz to 10.0 Hz                                                                                                                                                                                                                                       |        | 7.5   |        | $\mu\text{V p-p}$      |
| Voltage Noise Density            | $e_N$                          | 1 kHz                                                                                                                                                                                                                                                   |        | 110   |        | nV/ $\sqrt{\text{Hz}}$ |
| Turn-On Settling Time            | $t_R$                          | $C_{IN} = 0$                                                                                                                                                                                                                                            |        | 10    |        | $\mu\text{s}$          |
| Long-Term Stability <sup>1</sup> | $\Delta V_O$                   | 1,000 h                                                                                                                                                                                                                                                 |        | 40    |        | ppm                    |
| Output Voltage Hysteresis        | $V_{O\_HYS}$                   |                                                                                                                                                                                                                                                         |        | 20    |        | ppm                    |
| Ripple Rejection Ratio           | RRR                            | $f_{IN} = 10 \text{ kHz}$                                                                                                                                                                                                                               |        | -70   |        | dB                     |
| Short Circuit to GND             | $I_{SC}$                       |                                                                                                                                                                                                                                                         |        | 40    |        | mA                     |
| Supply Voltage Operating Range   | $V_{IN}$                       |                                                                                                                                                                                                                                                         | 6.5    |       | 18     | V                      |
| Supply Voltage Headroom          | $V_{IN} - V_O$                 |                                                                                                                                                                                                                                                         | 2      |       |        | V                      |

<sup>1</sup> The long-term stability specification is noncumulative. The drift in subsequent 1,000 hour periods is significantly lower than in the first 1,000 hour period.



## ABSOLUTE MAXIMUM RATINGS

@ 25°C, unless otherwise noted.

Table 8.

| Parameter                                  | Rating          |
|--------------------------------------------|-----------------|
| Supply Voltage                             | 20 V            |
| Output Short-Circuit Duration to GND       | Indefinite      |
| Storage Temperature Range (R, RM Packages) | –65°C to +125°C |
| Operating Temperature Range                | –40°C to +125°C |
| Junction Temperature Range                 | –65°C to +150°C |
| Lead Temperature Range (Soldering, 60 s)   | 300°C           |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Absolute maximum ratings apply individually only, not in combination.

## PACKAGE TYPE

Table 9.

| Package Type     | $\theta_{JA}^1$ | $\theta_{JC}$ | Unit |
|------------------|-----------------|---------------|------|
| 8-Lead SOIC (R)  | 130             | 43            | °C/W |
| 8-Lead MSOP (RM) | 190             |               | °C/W |

<sup>1</sup>  $\theta_{JA}$  is specified for worst-case conditions (device soldered in circuit board for surface-mount packages).

## ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



# ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

## TYPICAL PERFORMANCE CHARACTERISTICS

Default conditions:  $\pm 5$  V,  $C_L = 5$  pF,  $G = 2$ ,  $R_g = R_f = 1$  k $\Omega$ ,  $R_L = 2$  k $\Omega$ ,  $V_O = 2$  V p-p, Frequency = 1 MHz,  $T_A = 25^\circ\text{C}$ .

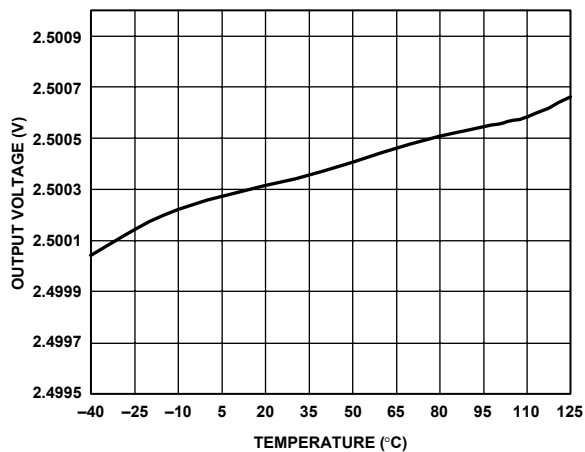


Figure 3. ADR431  $V_{OUT}$  vs. Temperature

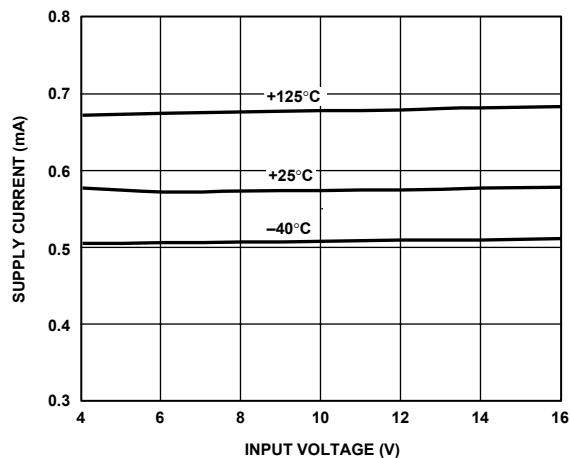


Figure 6. ADR435 Supply Current vs. Input Voltage

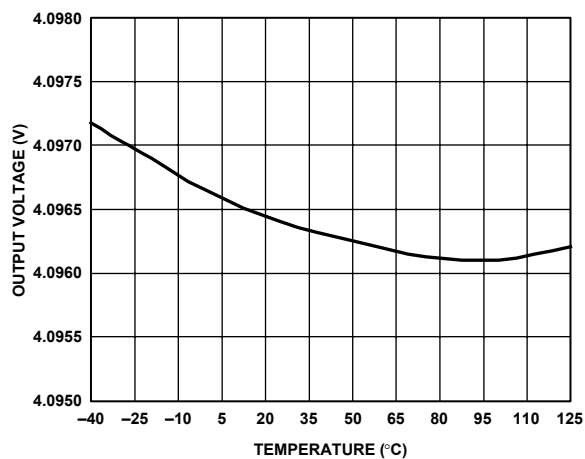


Figure 4. ADR434  $V_{OUT}$  vs. Temperature

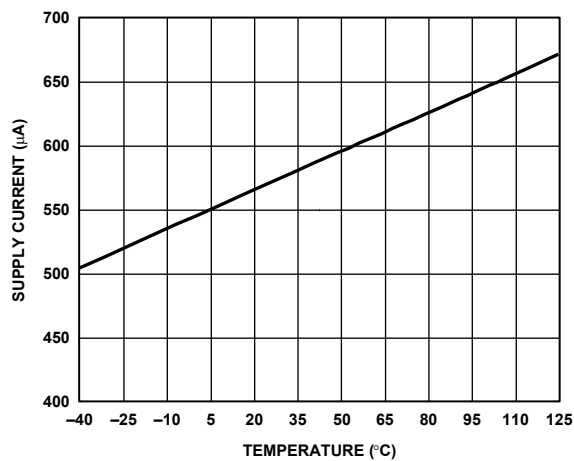


Figure 7. ADR435 Supply Current vs. Temperature

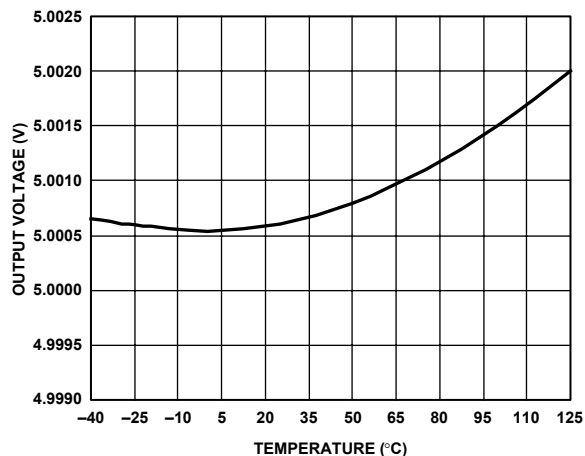


Figure 5. ADR435  $V_{OUT}$  vs. Temperature

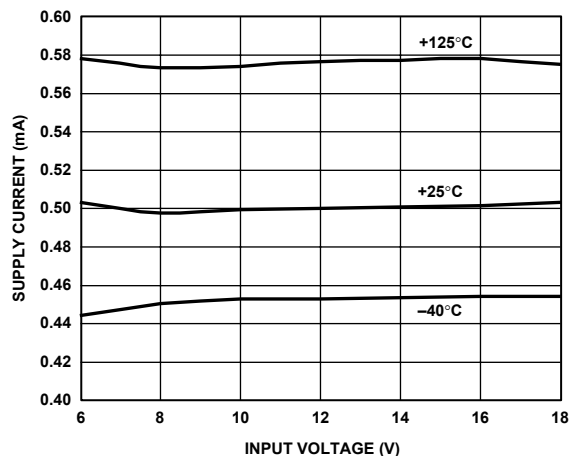


Figure 8. ADR431 Supply Current vs. Input Voltage

# ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

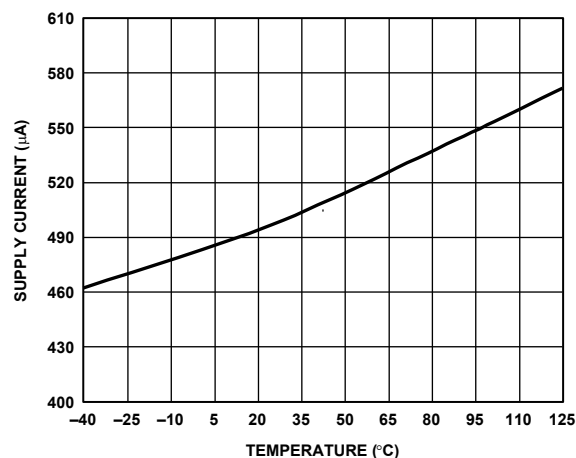


Figure 9. ADR431 Supply Current vs. Temperature

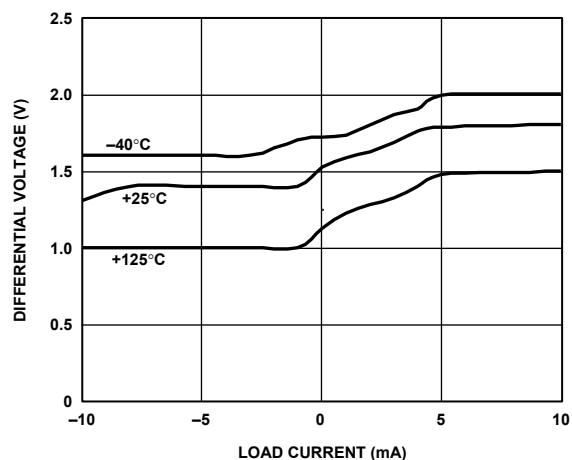


Figure 12. ADR431 Minimum Input/Output Differential Voltage vs. Load Current

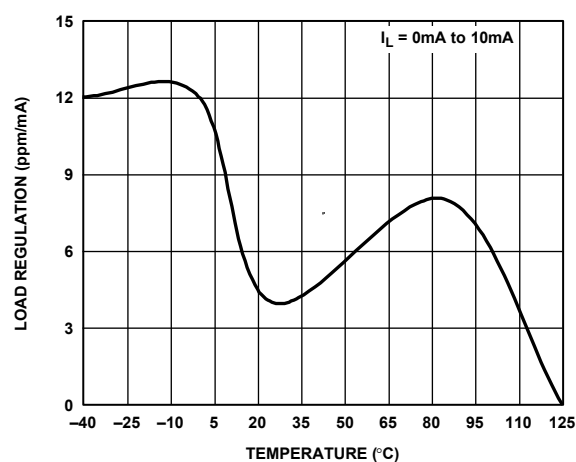


Figure 10. ADR431 Load Regulation vs. Temperature

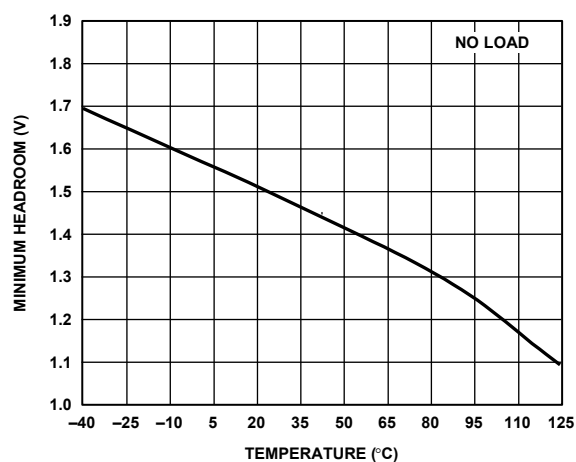


Figure 13. ADR431 Minimum Headroom vs. Temperature

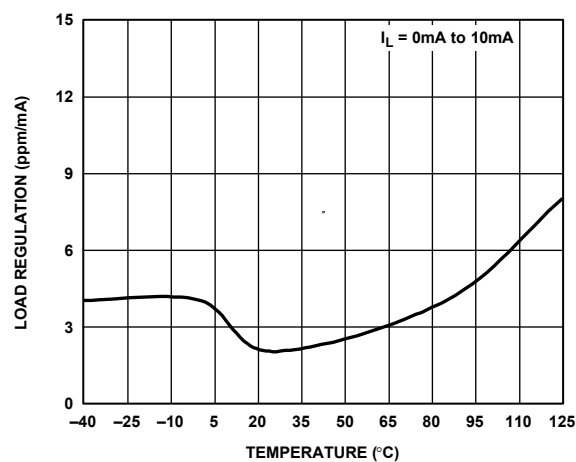


Figure 11. ADR435 Load Regulation vs. Temperature

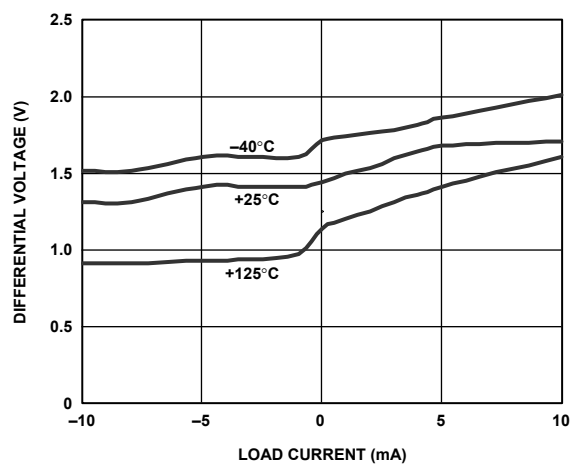


Figure 14. ADR435 Minimum Input/Output Differential Voltage vs. Load Current

ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

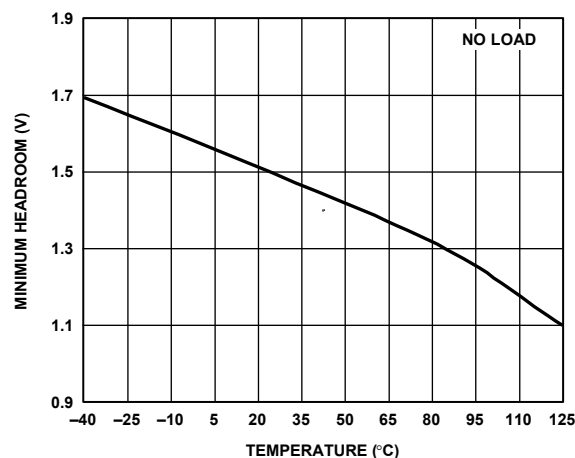


Figure 15. ADR435 Minimum Headroom vs. Temperature

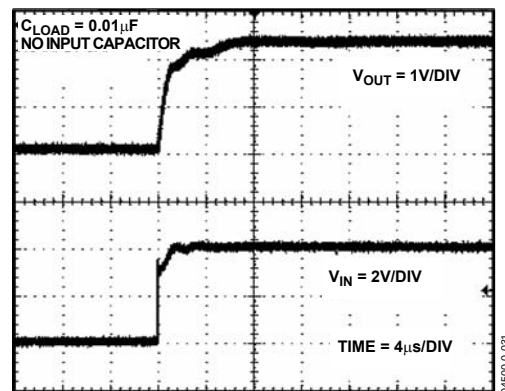


Figure 18. ADR431 Turn-On Response, 0.01  $\mu F$  Load Capacitor

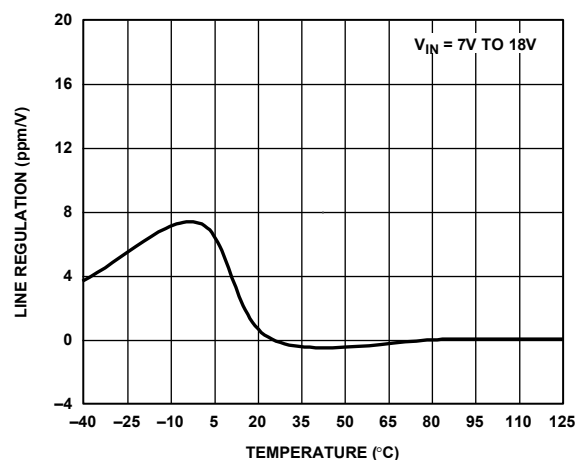


Figure 16. ADR435 Line Regulation vs. Temperature

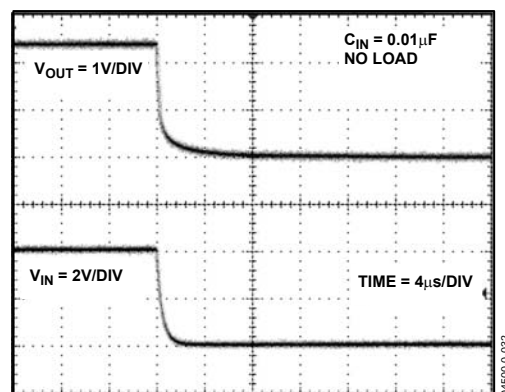


Figure 19. ADR431 Turn-Off Response

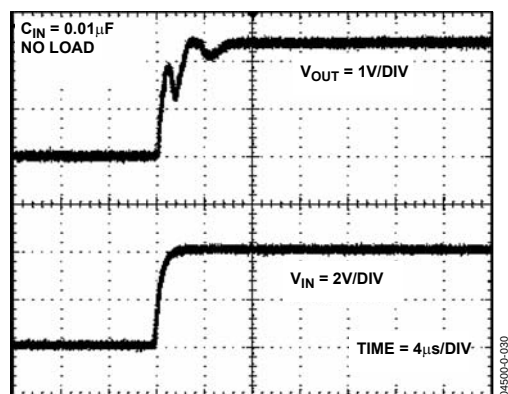


Figure 17. ADR431 Turn-On Response

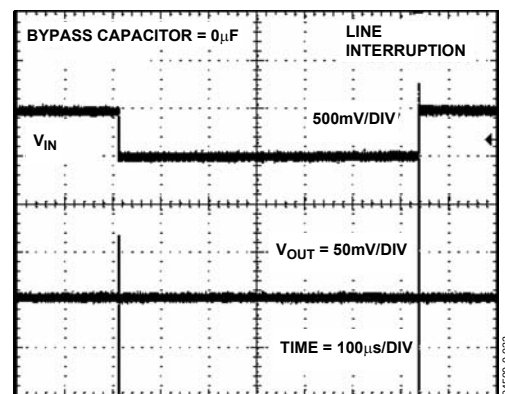


Figure 20. ADR431 Line Transient Response—No Capacitors

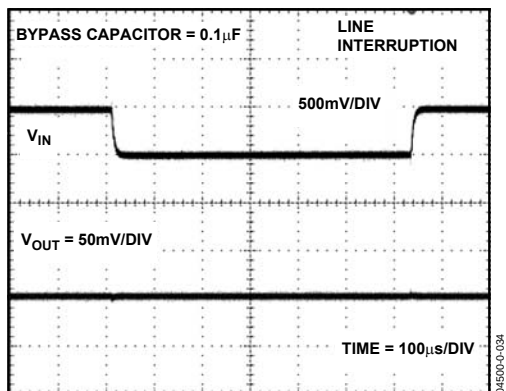


Figure 21. ADR431 Line Transient Response—0.1  $\mu$ F Bypass Capacitor

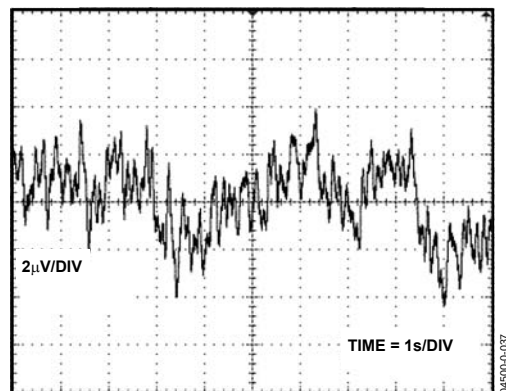


Figure 24. ADR435 0.1 Hz to 10.0 Hz Voltage Noise

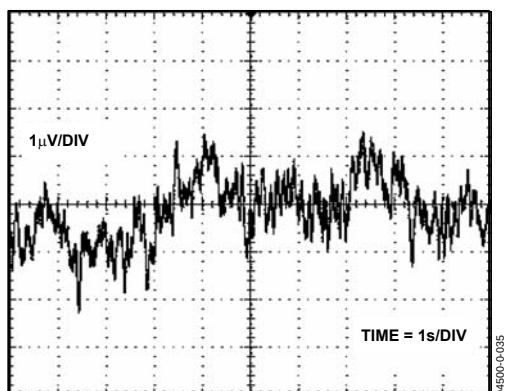


Figure 22. ADR431 0.1 Hz to 10.0 Hz Voltage Noise

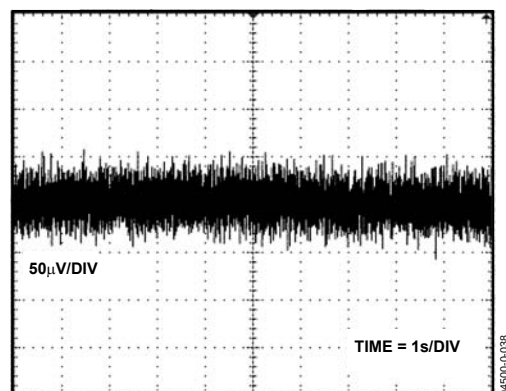


Figure 25. ADR435 10 Hz to 10 kHz Voltage Noise

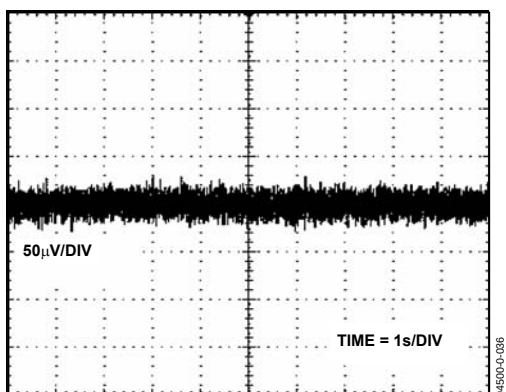


Figure 23. ADR431 10 Hz to 10 kHz Voltage Noise

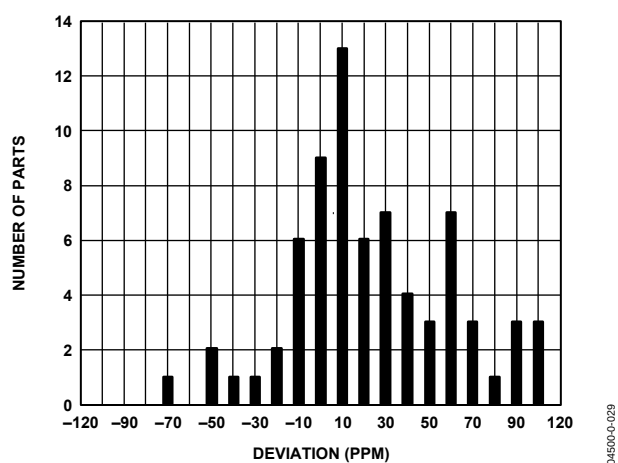


Figure 26. ADR431 Typical Hysteresis

ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

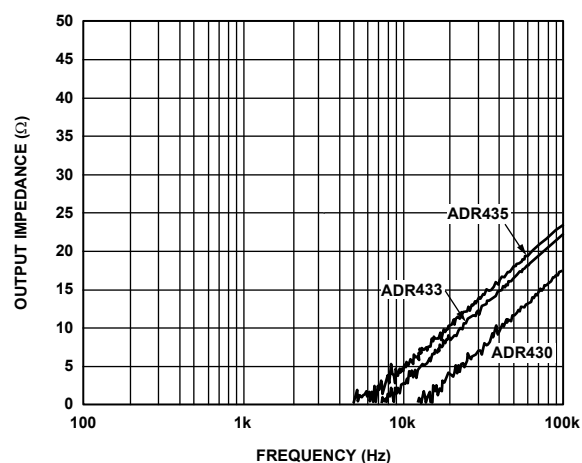


Figure 27. Output Impedance vs. Frequency

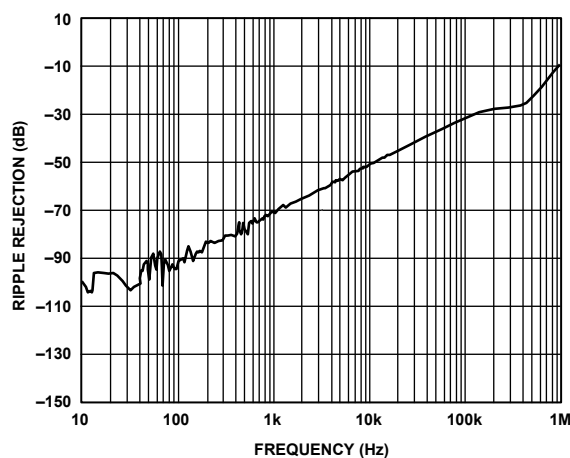


Figure 28. Ripple Rejection Ratio

## THEORY OF OPERATION

The ADR43x series of references uses a new reference generation technique known as XFET (eXtra implanted junction FET). This technique yields a reference with low supply current, good thermal hysteresis, and exceptionally low noise. The core of the XFET reference consists of two junction field-effect transistors (JFETs), one of which has an extra channel implant to raise its pinch-off voltage. By running the two JFETs at the same drain current, the difference in pinch-off voltage can be amplified and used to form a highly stable voltage reference.

The intrinsic reference voltage is around 0.5 V with a negative temperature coefficient of about  $-120 \text{ ppm}/^\circ\text{C}$ . This slope is essentially constant to the dielectric constant of silicon and can be closely compensated by adding a correction term generated in the same fashion as the proportional-to-temperature (PTAT) term used to compensate band gap references. The big advantage of an XFET reference is that the correction term is some 30 times lower (therefore, requiring less correction) than for a band gap reference, resulting in much lower noise, because most of the noise of a band gap reference comes from the temperature compensation circuitry.

Figure 29 shows the basic topology of the ADR43x series. The temperature correction term is provided by a current source with a value designed to be proportional to absolute temperature. The general equation is

$$V_{OUT} = G \times (\Delta V_P - R1 \times I_{PTAT}) \quad (1)$$

where:

$G$  is the gain of the reciprocal of the divider ratio.

$\Delta V_P$  is the difference in pinch-off voltage between the two JFETs.

$I_{PTAT}$  is the positive temperature coefficient correction current.

ADR43x devices are created by on-chip adjustment of  $R2$  and  $R3$  to achieve 2.048 V or 2.500 V, respectively, at the reference output.

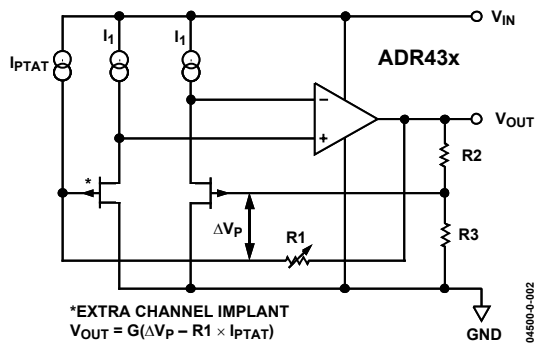


Figure 29. Simplified Schematic Device Power Dissipation Considerations

The ADR43x family of references is guaranteed to deliver load currents to 10 mA with an input voltage that ranges from 4.5 V to 18 V. When these devices are used in applications at higher currents, users should use the following equation to account for the temperature effects due to the power dissipation increases.

$$T_J = P_D \times \theta_{JA} + T_A \quad (2)$$

where:

$T_J$  and  $T_A$  are the junction and ambient temperatures, respectively.

$P_D$  is the device power dissipation.

$\theta_{JA}$  is the device package thermal resistance.

## BASIC VOLTAGE REFERENCE CONNECTIONS

Voltage references, in general, require a bypass capacitor connected from  $V_{OUT}$  to GND. The circuit in Figure 30 illustrates the basic configuration for the ADR43x family of references. Other than a 0.1  $\mu\text{F}$  capacitor at the output to help improve noise suppression, a large output capacitor at the output is not required for circuit stability.

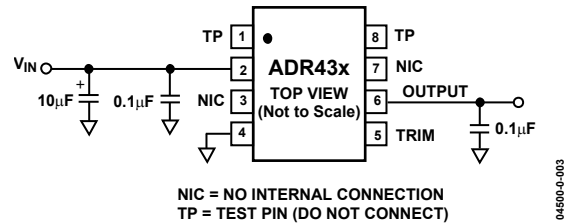


Figure 30. Basic Voltage Reference Configuration

## NOISE PERFORMANCE

The noise generated by the ADR43x family of references is typically less than 3.75  $\mu\text{V}$  p-p over the 0.1 Hz to 10.0 Hz band for ADR430, ADR431, and ADR433. Figure 22 shows the 0.1 Hz to 10 Hz noise of the ADR431, which is only 3.5  $\mu\text{V}$  p-p. The noise measurement is made with a band-pass filter made of a 2-pole high-pass filter with a corner frequency at 0.1 Hz and a 2-pole low-pass filter with a corner frequency at 10.0 Hz.

## TURN-ON TIME

Upon application of power (cold start), the time required for the output voltage to reach its final value within a specified error band is defined as the turn-on settling time. Two components normally associated with this are the time for the active circuits to settle and the time for the thermal gradients on the chip to stabilize. Figure 17 and Figure 18 show the turn-on settling time for the ADR431.

## APPLICATIONS

### OUTPUT ADJUSTMENT

The ADR43x trim terminal can be used to adjust the output voltage over a  $\pm 0.5\%$  range. This feature allows the system designer to trim system errors out by setting the reference to a voltage other than the nominal. This is also helpful if the part is used in a system at temperature to trim out any error. Adjustment of the output has negligible effect on the temperature performance of the device. To avoid degrading temperature coefficients, both the trimming potentiometer and the two resistors need to be low temperature coefficient types, preferably  $<100 \text{ ppm}/^\circ\text{C}$ .

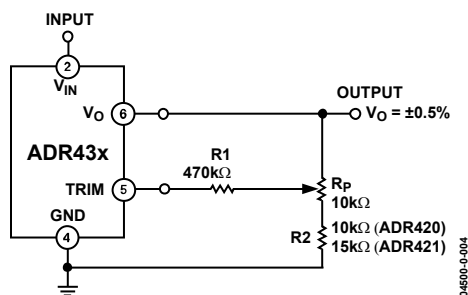


Figure 31. Output Trim Adjustment

### REFERENCE FOR CONVERTERS IN OPTICAL NETWORK CONTROL CIRCUITS

In the upcoming high capacity, all-optical router network, Figure 32 employs arrays of micromirrors to direct and route optical signals from fiber to fiber without first converting them to electrical form, which reduces the communication speed. The tiny micromechanical mirrors are positioned so that each is illuminated by a single wavelength that carries unique information and can be passed to any desired input and output fiber. The mirrors are tilted by the dual-axis actuators controlled by precision ADCs and DACs within the system. Due to the microscopic movement of the mirrors, not only is the precision of the converters important, but the noise associated with these controlling converters is also extremely critical, because total noise within the system can be multiplied by the number of converters employed. As a result, to maintain the stability of the control loop for this application, the ADR43x is necessary due to its exceptionally low noise.

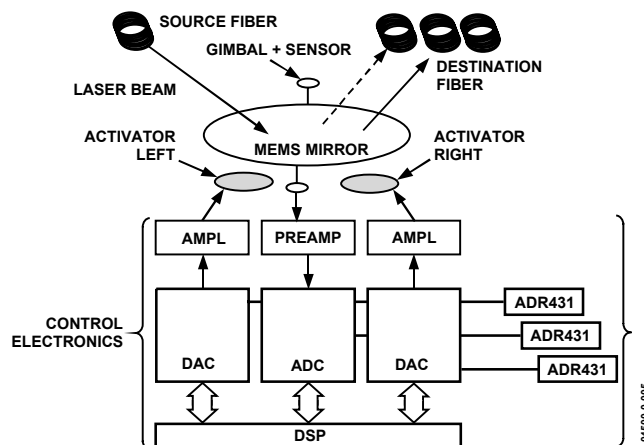


Figure 32. All-Optical Router Network

### NEGATIVE PRECISION REFERENCE WITHOUT PRECISION RESISTORS

In many current-output CMOS DAC applications where the output signal voltage must be of the same polarity as the reference voltage, it is often required to reconfigure a current-switching DAC into a voltage-switching DAC through the use of a 1.25 V reference, an op amp, and a pair of resistors. Using a current-switching DAC directly requires an additional operational amplifier at the output to re-invert the signal. A negative voltage reference is then desirable from the standpoint that an additional operational amplifier is not required for either re-inversion (current-switching mode) or amplification (voltage-switching mode) of the DAC output voltage. In general, any positive voltage reference can be converted into a negative voltage reference through the use of an operational amplifier and a pair of matched resistors in an inverting configuration. The disadvantage to this approach is that the largest single source of error in the circuit is the relative matching of the resistors used.

A negative reference can easily be generated by adding a precision op amp and configuring it as shown in Figure 33.  $V_{OUT}$  is at virtual ground and, therefore, the negative reference can be taken directly from the output of the op amp. The op amp must be dual supply, have low offset and rail-to-rail capability, if negative supply voltage is close to the reference output.

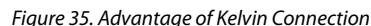




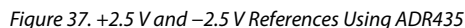
The circuit in Figure 34 can be used to generate a floating current source with minimal self-heating. This particular configuration can operate on high supply voltages determined by the breakdown voltage of the N-channel JFET.



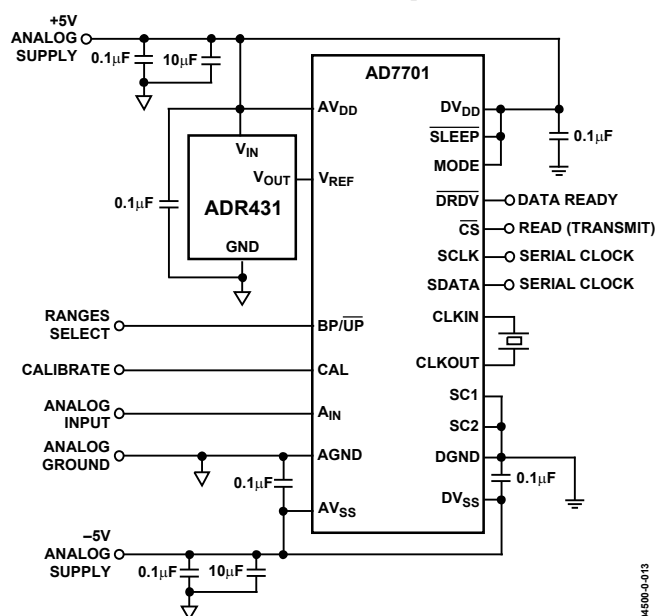
In many portable instrumentation applications where PC board cost and area go hand-in-hand, circuit interconnects are very often of dimensionally minimum width. These narrow lines can cause large voltage drops if the voltage reference is required to provide load currents to various functions. In fact, a circuit's interconnects can exhibit a typical line resistance of 0.45 mΩ/square (1 oz. Cu, for example). Force and sense connections, also referred to as Kelvin connections, offer a convenient method of eliminating the effects of voltage drops in circuit wires. Load currents flowing through wiring resistance produce an error ( $V_{\text{ERROR}} = R \times I_L$ ) at the load. However, the Kelvin connection of Figure 35 overcomes the problem by including the wiring resistance within the forcing loop of the op amp. Because the op amp senses the load voltage, the op amp loop control forces the output to compensate for the wiring error and to produce the correct voltage at the load.



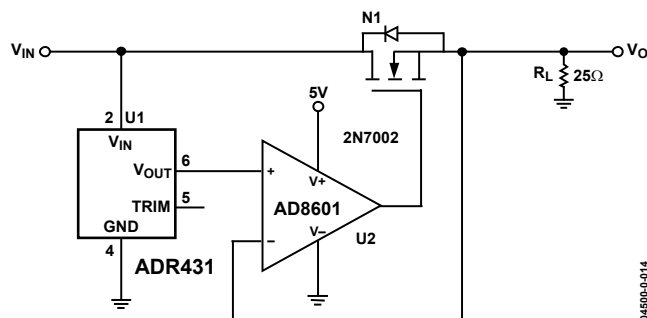
Dual polarity references can easily be made with an op amp and a pair of resistors. In order not to defeat the accuracy obtained by ADR43x, it is imperative to match the resistance tolerance as well as the temperature coefficient of all the components.







## PRECISION BOOSTED OUTPUT REGULATOR



# ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

## OUTLINE DIMENSIONS

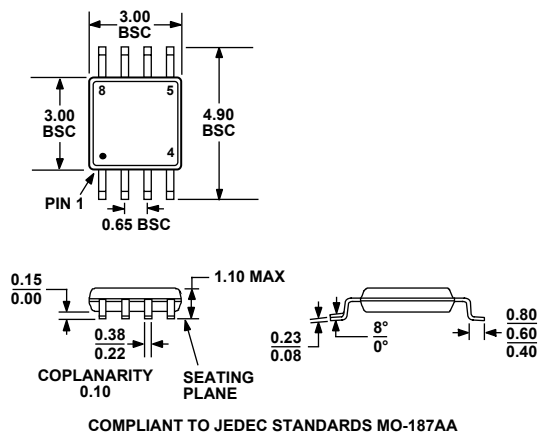


Figure 42. 8-Lead Mini Small Outline Package [MSOP]  
(RM-8)  
Dimensions shown in millimeters

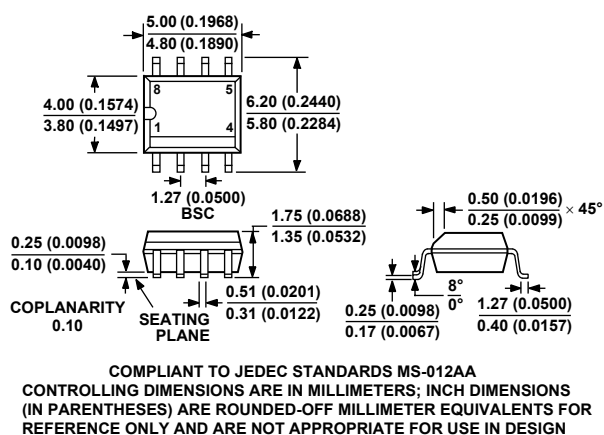


Figure 43. 8-Lead Standard Small Outline Package [SOIC]  
Narrow Body (R-8)  
Dimensions shown in millimeters and (inches)

# ADR430/ADR431/ADR433/ADR434/ADR435/ADR439

## ORDERING GUIDE

| Model           | Output Voltage (V <sub>o</sub> ) | Initial Accuracy |      | Temperature Coefficient Package (ppm/°C) | Package Description | Parts per Reel | Branding | Temperature Range |
|-----------------|----------------------------------|------------------|------|------------------------------------------|---------------------|----------------|----------|-------------------|
|                 |                                  | mV               | (%)  |                                          |                     |                |          |                   |
| ADR430AR        | 2.048                            | 3                | 0.15 | 10                                       | 8-lead SOIC         | N/A            | RHA      | –40°C to +125°C   |
| ADR430AR-REEL7  | 2.048                            | 3                | 0.15 | 10                                       | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR430ARM       | 2.048                            | 3                | 0.15 | 10                                       | 8-Lead MSOP         | N/A            |          | –40°C to +125°C   |
| ADR430ARM-REEL7 | 2.048                            | 3                | 0.15 | 10                                       | 8-Lead MSOP         | 1,000          |          | –40°C to +125°C   |
| ADR430BR        | 2.048                            | 1                | 0.05 | 3                                        | 8-lead SOIC         | N/A            |          | –40°C to +125°C   |
| ADR430BR-REEL7  | 2.048                            | 1                | 0.05 | 3                                        | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR431AR        | 2.500                            | 3                | 0.12 | 10                                       | 8-Lead SOIC         | N/A            | RJA      | –40°C to +125°C   |
| ADR431AR-REEL7  | 2.500                            | 3                | 0.12 | 10                                       | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR431ARM       | 2.500                            | 3                | 0.12 | 10                                       | 8-Lead MSOP         | N/A            |          | –40°C to +125°C   |
| ADR431ARM-REEL7 | 2.500                            | 3                | 0.12 | 10                                       | 8-Lead MSOP         | 1,000          |          | –40°C to +125°C   |
| ADR431BR        | 2.500                            | 1                | 0.04 | 3                                        | 8-Lead SOIC         | N/A            |          | –40°C to +125°C   |
| ADR431BR-REEL7  | 2.500                            | 1                | 0.04 | 3                                        | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR433AR        | 3.000                            | 4                | 0.12 | 10                                       | 8-Lead SOIC         | N/A            | RKA      | –40°C to +125°C   |
| ADR433AR-REEL7  | 3.000                            | 4                | 0.12 | 10                                       | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR433ARM       | 3.000                            | 4                | 0.12 | 10                                       | 8-Lead MSOP         | N/A            |          | –40°C to +125°C   |
| ADR433ARM-REEL7 | 3.000                            | 4                | 0.12 | 10                                       | 8-Lead MSOP         | 1,000          |          | –40°C to +125°C   |
| ADR433BR        | 3.000                            | 1.5              | 0.05 | 3                                        | 8-Lead SOIC         | N/A            |          | –40°C to +125°C   |
| ADR433BR-REEL7  | 3.000                            | 1.5              | 0.05 | 3                                        | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR434AR        | 4.096                            | 5                | 0.13 | 10                                       | 8-Lead SOIC         | N/A            | RLA      | –40°C to +125°C   |
| ADR434AR-REEL7  | 4.096                            | 5                | 0.13 | 10                                       | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR434ARM       | 4.096                            | 5                | 0.13 | 10                                       | 8-Lead MSOP         | N/A            |          | –40°C to +125°C   |
| ADR434ARM-REEL7 | 4.096                            | 5                | 0.13 | 10                                       | 8-Lead MSOP         | 1,000          |          | –40°C to +125°C   |
| ADR434BR        | 4.096                            | 1.5              | 0.04 | 3                                        | 8-Lead SOIC         | N/A            |          | –40°C to +125°C   |
| ADR434BR-REEL7  | 4.096                            | 1.5              | 0.04 | 3                                        | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR435AR        | 5.000                            | 6                | 0.12 | 10                                       | 8-Lead SOIC         | N/A            | RMA      | –40°C to +125°C   |
| ADR435AR-REEL7  | 5.000                            | 6                | 0.12 | 10                                       | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR435ARM       | 5.000                            | 6                | 0.12 | 10                                       | 8-Lead MSOP         | N/A            |          | –40°C to +125°C   |
| ADR435ARM-REEL7 | 5.000                            | 6                | 0.12 | 10                                       | 8-Lead MSOP         | 1,000          |          | –40°C to +125°C   |
| ADR435BR        | 5.000                            | 2                | 0.04 | 3                                        | 8-Lead SOIC         | N/A            |          | –40°C to +125°C   |
| ADR435BR-REEL7  | 5.000                            | 2                | 0.04 | 3                                        | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR439AR        | 4.500                            | 5.4              | 0.12 | 10                                       | 8-Lead SOIC         | N/A            | RNA      | –40°C to +125°C   |
| ADR439AR-REEL7  | 4.500                            | 5.4              | 0.12 | 10                                       | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |
| ADR439ARM       | 4.500                            | 5.4              | 0.12 | 10                                       | 8-Lead MSOP         | N/A            |          | –40°C to +125°C   |
| ADR439ARM-REEL7 | 4.500                            | 5.4              | 0.12 | 10                                       | 8-Lead MSOP         | 1,000          |          | –40°C to +125°C   |
| ADR439BR        | 4.500                            | 2                | 0.04 | 3                                        | 8-Lead SOIC         | N/A            |          | –40°C to +125°C   |
| ADR439BR-REEL7  | 4.500                            | 2                | 0.04 | 3                                        | 8-Lead SOIC         | 3,000          |          | –40°C to +125°C   |

**ADR430/ADR431/ADR433/ADR434/ADR435/ADR439**

**NOTES**

**NOTES**

**ADR430/ADR431/ADR433/ADR434/ADR435/ADR439**

## **NOTES**